

#### **General Description**

The WSF3036 is the highest performance trench N-ch MOSFETs with extreme high cell density , which provide excellent  $R_{\text{DSON}}$  and gate charge for most of the synchronous buck converter applications .

The WSF3036 meet the RoHS and Green Product requirement , 100% EAS guaranteed with full function reliability approved.

#### Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline

**Absolute Maximum Ratings** 

- 100% EAS Guaranteed
- Green Device Available

#### **Product Summery**

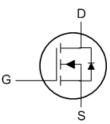
BVDSS	RDSON	ID
30V	16mΩ	36A

#### Applications

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

#### **TO-252 Pin Configuration**





Symbol	Parameter	Rating	Units
V <sub>DS</sub>	Drain-Source Voltage	30	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub> @T <sub>C</sub> =25℃	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	36	А
I <sub>D</sub> @T <sub>C</sub> =100℃	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	26	А
I <sub>DM</sub>	Pulsed Drain Current <sup>2</sup>	58	А
EAS	Single Pulse Avalanche Energy <sup>3</sup>	70	mJ
I <sub>AS</sub>	Avalanche Current	20	А
P <sub>D</sub> @T <sub>C</sub> =25℃	Total Power Dissipation <sup>4</sup>	22	W
T <sub>STG</sub>	Storage Temperature Range -55 to 150		°C
TJ	Operating Junction Temperature Range	-55 to 150	°C

### **Thermal Data**

Symbol	Parameter	Тур.	Max.	Unit
R <sub>θJA</sub>	Thermal Resistance Junction-Ambient (<10s) <sup>1</sup>		25	°C/W
R <sub>θJA</sub>	Thermal Resistance Junction-ambient (Steady State) <sup>1</sup>		62	°C/W
R <sub>θJC</sub>	Thermal Resistance Junction-Case <sup>1</sup>		5	°C/W



**N-Ch MOSFET** 

#### Electrical Characteristics (T<sub>J</sub>=25<sup>-1</sup>C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V , I <sub>D</sub> =250uA	30			V
$\triangle BV_{DSS} / \triangle T_J$	BVDSS Temperature Coefficient	Reference to 25 $^\circ\!\mathrm{C}$ , I_D=1mA		0.023		V/℃
В	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =10V , I <sub>D</sub> =10A		16	26	mΩ
R <sub>DS(ON)</sub>		V <sub>GS</sub> =4.5V , I <sub>D</sub> =5A		25	38	1115.2
V <sub>GS(th)</sub>	Gate Threshold Voltage		1.0	1.5	2.5	V
_V <sub>GS(th)</sub>	V <sub>GS(th)</sub> Temperature Coefficient	$V_{GS}=V_{DS}$ , $I_{D}=250$ uA		-5.2		mV/℃
		$V_{DS}$ =24V , $V_{GS}$ =0V , $T_J$ =25 $^{\circ}$ C			1	
I <sub>DSS</sub>	Drain-Source Leakage Current	$V_{DS}$ =24V , $V_{GS}$ =0V , TJ=55 $^{\circ}$ C			5	uA
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}=\pm20V$ , $V_{DS}=0V$			±100	nA
gfs	Forward Transconductance	V <sub>DS</sub> =15V , I <sub>D</sub> =10A		10		S
Rg	Gate Resistance	V <sub>DS=</sub> 24V , V <sub>GS</sub> =0V , f=1MHz		2.5		Ω
Qg	Total Gate Charge (4.5V)	V <sub>DS=</sub> 20V , V <sub>GS</sub> =4.5V , I <sub>D</sub> =10A		7.0		
Q <sub>gs</sub>	Gate-Source Charge			1.3		nC
Q <sub>gd</sub>	Gate-Drain Charge			2.4		
T <sub>d(on)</sub>	Turn-On Delay Time	V <sub>DD</sub> =12V , V <sub>GS</sub> =10V , R <sub>G</sub> =3.3Ω,		4.0		
Tr	Rise Time			9.2		
T <sub>d(off)</sub>	Turn-Off Delay Time			21		ns
T <sub>f</sub>	Fall Time			5.8		
Ciss	Input Capacitance	V <sub>DS</sub> =25V , V <sub>GS</sub> =0V , f=1MHz		530		
C <sub>oss</sub>	Output Capacitance			65		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			50		

#### **Guaranteed Avalanche Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
EAS	Single Pulse Avalanche Energy $^5$	V <sub>DD</sub> =25V , L=0.1mH , I <sub>AS</sub> =10A	16			mJ

#### **Diode Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current <sup>1,6</sup>	$V_G = V_D = 0V$ , Force Current			9.5	А
I <sub>SM</sub>	Pulsed Source Current <sup>2,6</sup>				55	А
V <sub>SD</sub>	Diode Forward Voltage <sup>2</sup>	V <sub>GS</sub> =0V , I <sub>S</sub> =15A , T <sub>j</sub> =25℃			1.2	V

Note :

1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper,t<10sec.

2.The data tested by pulsed , pulse width  $\,\leq\,$  300us , duty cycle  $\,\leq\,$  2%

3. The EAS data shows Max. rating . The test condition is  $V_{DD}$ =25V,  $V_{GS}$ =10V, L=0.1mH,  $I_{AS}$ =10A

5.The Min. value is 100% EAS tested guarantee.

6. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.

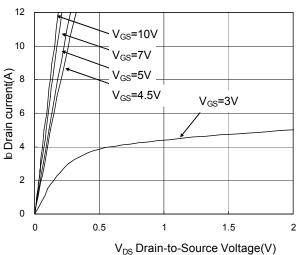
<sup>4.</sup>The power dissipation is limited by 150  $^\circ\!\!\!\mathrm{C}$  junction temperature



# WSF3036

N-Ch MOSFET





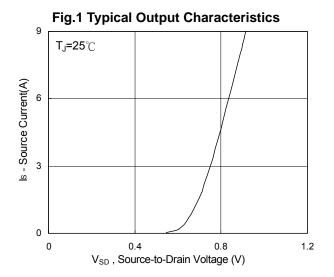
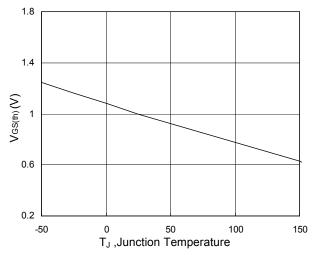


Fig.3 Forward characteristics of reverse



(°C) Fig.5 V<sub>GS(th)</sub> vs. T<sub>J</sub>

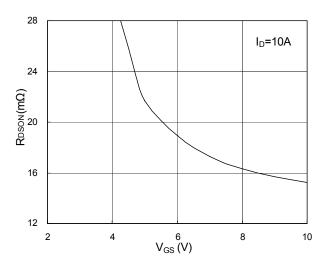


Fig.2 On-Resistance vs. G-S Voltage

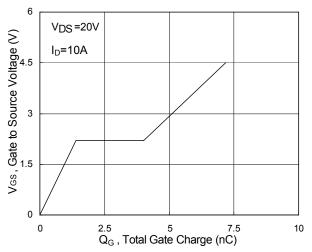


Fig.4 Gate-charge characteristics

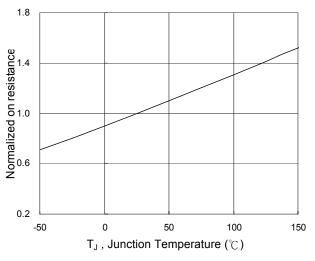
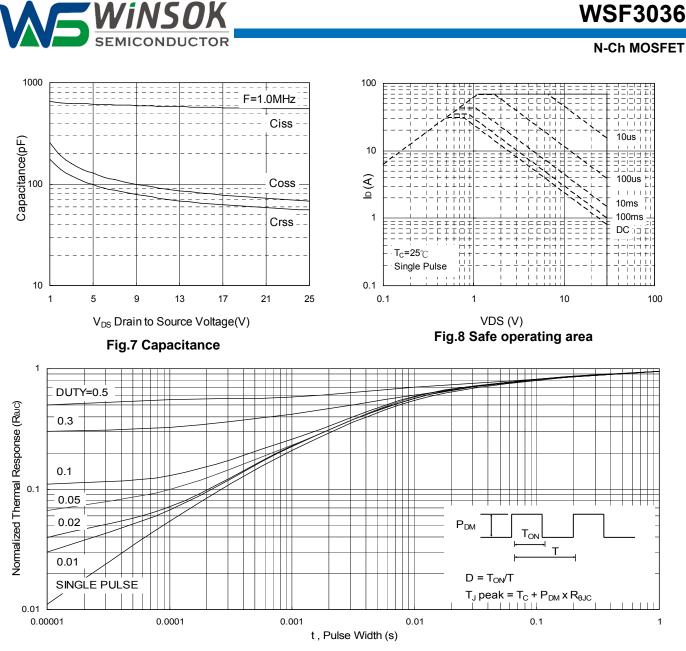
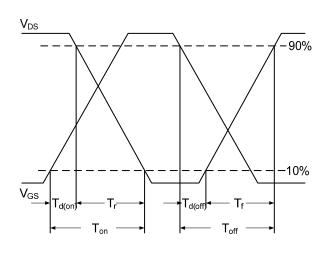
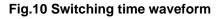


Fig.6 Normalized  $R_{\text{DSON}}$  vs.  $T_{\text{J}}$ 









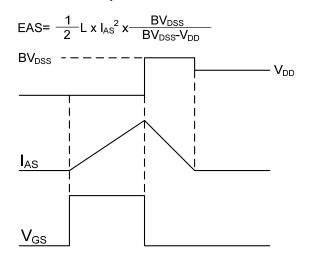


Fig.11 Unclamped inductive switching wave.



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